Features

- Industry-standard Architecture
  - Low-cost, Easy-to-use Software Tools
- High-speed, Electrically Erasable Programmable Logic Devices
  - 5 ns Maximum Pin-to-pin Delay
- Latch Feature Holds Inputs to Previous Logic States
- Pin-controlled Standby Power (10 µA Typical)
- Advanced Flash Technology
  - Reprogrammable
  - 100% Tested
- High-reliability CMOS Process
  - 20-year Data Retention
  - 100 Erase/Write Cycles
  - 2,000V ESD Protection
  - 200 mA Latch-up Immunity
- Dual Inline and Surface Mount Packages in Standard Pinouts
- PCI-compliant
- Green Package Options (Pb/Halide-free/RoHS Compliant) Available
- Full Military, Commercial and Industrial Temperature Ranges
- Backward-Compatible with ATF22V10B(Q) and AT22V10(L)

1. Description

The ATF22V10C is a high-performance CMOS (electrically erasable) programmable logic device (PLD) that utilizes Atmel's proven electrically erasable Flash memory technology. Speeds down to 5 ns and power dissipation as low as 100 µA are offered. All speed ranges are specified over the full 5V ± 10% range for military and industrial temperature ranges, and 5V ± 5% for commercial temperature ranges.

Several low-power options allow selection of the best solution for various types of power-limited applications. Each of these options significantly reduces total system power and enhances system reliability.

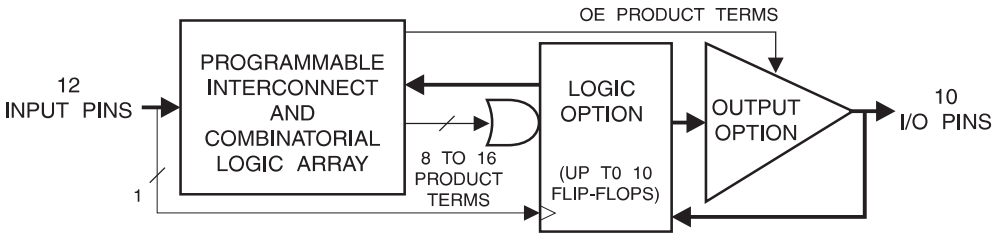
High-performance EE PLD

ATF22V10C
ATF22V10CQ

See separate datasheet for the ATF22V10CQZ.

0735T–PLD–5/09

Figure 1-1. Logic Diagram



2. Pin Configurations

Table 2-1. Pin Configurations (All Pinouts Top View)

Pin Name	Function
CLK	Clock
IN	Logic Inputs
I/O	Bi-directional Buffers
GND	Ground
VCC	+5V Supply
PD	Power-down

Figure 2-1. TSSOP

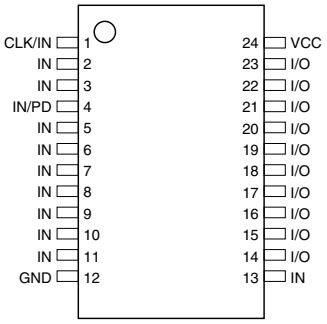


Figure 2-2. DIP/SOIC

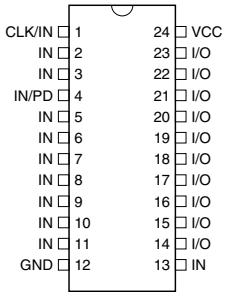
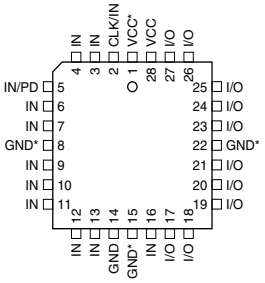


Figure 2-3. PLCC/LCC



Note: For all PLCCs (except “-5”), pins 1, 8, 15 and 22 can be left unconnected. However, if they are connected, superior performance will be achieved.

3. Absolute Maximum Ratings*

Temperature under Bias	-55°C to +125°C
Storage Temperature	-65°C to +150°C
Voltage on Any Pin with Respect to Ground	-2.0V to +7.0V(1)
Voltage on Input Pins with Respect to Ground during Programming	-2.0V to +14.0V(1)
Programming Voltage with Respect to Ground	-2.0V to +14.0V(1)

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: 1. Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC} + 0.75V DC, which may overshoot to 7.0V for pulses of less than 20 ns.

4. DC and AC Operating Conditions

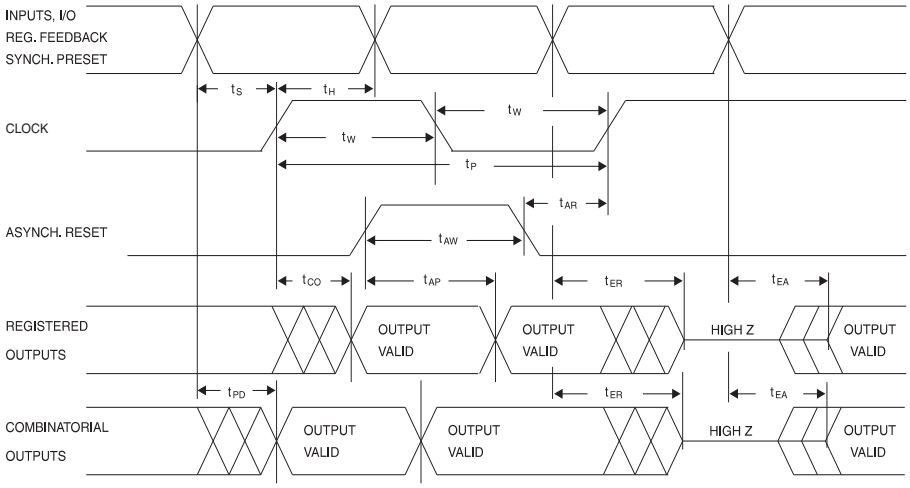
	Commercial	Industrial	Military
Operating Temperature (Ambient)	0°C - 70°C	-40°C - 85°C	-55°C - 125°C (case)
V_{CC} Power Supply	5V ± 5%	5V ± 10%	5V ± 10%

4.1 DC Characteristics

Symbol	Parameter	Condition			Min	Typ	Max	Units
I_{IL}	Input or I/O Low Leakage Current	$0 \le V_{IN} \le V_{IL}$ (Max)					-10.0	µA
I_{IH}	Input or I/O High Leakage Current	$3.5 \le V_{IN} \le V_{CC}$					10.0	µA
I_{CC}	Power Supply Current, Standby	V_{CC} = Max, V_{IN} = Max, Outputs Open	C-5, 7, 10	Com.		85.0	130.0	mA
			C-10	Ind., Mil.		90.0	140.0	mA
			C-15	Com.		65.0	90.0	mA
			C-15	Ind., Mil.		65.0	115.0	mA
			CQ-15	Com.		35.0	55.0	mA
			CQ-15	Ind.		35.0	70.0	mA
I_{CC2}	Clocked Power Supply Current	V_{CC} = Max, Outputs Open, f = 15 MHz	C-5, 7, 10	Com.			150.0	mA
			C-10	Ind., Mil.			160.0	mA
			C-15	Com.		70.0	90.0	mA
			C-15	Ind., Mil.		70.0	90.0	mA
			CQ-15	Com.		40.0	60.0	mA
			CQ-15	Ind.		40.0	80.0	mA
I_{PD}	Power Supply Current, PD Mode	V_{CC} = Max		Com.		10.0	100.0	µA
		V_{IN} = 0, Max		Ind.		10.0	100.0	µA
I_{OS}[1]	Output Short Circuit Current	V_{OUT} = 0.5V					-130.0	mA
V_{IL}	Input Low Voltage				-0.5		0.8	V
V_{IH}	Input High Voltage				2.0		V_{CC}+0.75	V
V_{OL}	Output Low Voltage	$V_{IN} = V_{IH}$ or V_{IL}, V_{CC} = Min	I_{OL} = 16 mA	Com., Ind.			0.5	V
			I_{OL} = 12 mA	Mil.			0.5	V
V_{OH}	Output High Voltage	$V_{IN} = V_{IH}$ or V_{IL}, V_{CC} = Min	I_{OH} = -4.0 mA		2.4			V

Note: 1. Not more than one output at a time should be shorted. Duration of short circuit test should not exceed 30 sec.

4.2 AC Waveforms [1]



Note: 1. Timing measurement reference is 1.5V. Input AC driving levels are 0.0V and 3.0V, unless otherwise specified.

4.3 AC Characteristics[1]

Symbol	Parameter	-5		-7		-10		-15		Units
		Min	Max	Min	Max	Min	Max	Min	Max	
t_{PD}	Input or Feedback to Combinatorial Output	1.0	5.0	3.0	7.5	3.0	10.0	3.0	15.0	ns
t_{CO}	Clock to Output	1.0	4.0	2.0	4.5[2]	2.0	6.5	2.0	8.0	ns
t_{CF}	Clock to Feedback		2.5		2.5		2.5		2.5	ns
t_S	Input or Feedback Setup Time	3.0		3.5		4.5		10.0		ns
t_H	Hold Time	0		0		0		0		ns
f_{MAX}	External Feedback $1/(t_S + t_{CO})$	142.0		125.0[3]		90.0		55.5		MHz
	Internal Feedback $1/(t_S + t_{CF})$	166.0		142.0		117.0		80.0		MHz
	No Feedback $1/(t_{WH} + t_{WL})$	166.0		166.0		125.0		83.3		MHz
t_W	Clock Width (t_{WL} and t_{WH})	3.0		3.0		3.0		6.0		ns
t_{EA}	Input or I/O to Output Enable	2.0	6.0	3.0	7.5	3.0	10.0	3.0	15.0	ns
t_{ER}	Input or I/O to Output Disable	2.0	5.0	3.0	7.5	3.0	9.0	3.0	15.0	ns
t_{AP}	Input or I/O to Asynchronous Reset of Register	3.0	7.0	3.0	10.0	3.0	12.0	3.0	20.0	ns
t_{AW}	Asynchronous Reset Width	5.5		7.0		8.0			15.0	ns
t_{AR}	Asynchronous Reset Recovery Time	4.0		5.0		6.0			10.0	ns
t_{SP}	Setup Time, Synchronous Preset	4.0		4.5		6.0			10.0	ns
t_{SPR}	Synchronous Preset to Clock Recovery Time	4.0		5.0		8.0			10.0	ns

Notes: 1. See ordering information for valid part numbers.
2. 5.5 ns for DIP package devices.
3. 111 MHz for DIP package devices.

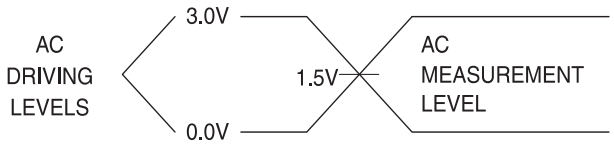
4.4 Power-down AC Characteristics[1][2][3]

Symbol	Parameter	-5		-7		-10		-15		Units
		Min	Max	Min	Max	Min	Max	Min	Max	
t_{IVDH}	Valid Input before PD High	5.0		7.5		10.0		15.0		ns
t_{GVDH}	Valid $\overline{OE}$ before PD High	0		0		0		0		ns
t_{CVDH}	Valid Clock before PD High	0		0		0				ns
t_{DHIX}	Input Don't Care after PD High		5.0		7.0		10.0		15.0	ns
t_{DHGX}	$\overline{OE}$ Don't Care after PD High		5.0		7.0		10.0		15.0	ns
t_{DHCX}	Clock Don't Care after PD High		5.0		7.0		10.0		15.0	ns
t_{DLIV}	PD Low to Valid Input		5.0		7.5		10.0		15.0	ns
t_{DLGV}	PD Low to Valid $\overline{OE}$		15.0		20.0		25.0		30.0	ns
t_{DLCV}	PD Low to Valid Clock		15.0		20.0		25.0		30.0	ns
t_{DLOV}	PD Low to Valid Output		20.0		25.0		30.0		35.0	ns

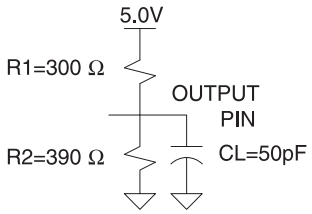
Notes: 1. Output data is latched and held.
2. High-Z outputs remain high-Z.
3. Clock and input transitions are ignored.

4.5 Input Test Waveforms

4.5.1 Input Test Waveforms and Measurement Levels



4.5.2 Commercial Output Test Loads



4.6 Pin Capacitance

Table 4-1. Pin Capacitance (f = 1 MHz, T = 25°C[1])

	Typ	Max	Units	Conditions
C_{IN}	5	8	pF	V_{IN} = 0V
C_{OUT}	6	8	pF	V_{OUT} = 0V

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.

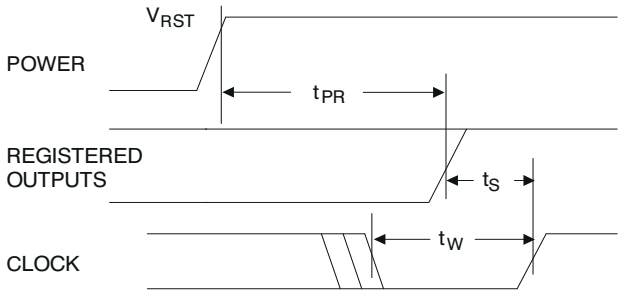
4.7 Power-up Reset

The registers in the ATF22V10Cs are designed to reset during power-up. At a point delayed slightly from V_{CC} crossing V_{RST}, all registers will be reset to the low state. The output state will depend on the polarity of the output buffer.

This feature is critical for state machine initialization. However, due to the asynchronous nature of reset and the uncertainty of how V_{CC} actually rises in the system, the following conditions are required:

1. The V_{CC} rise must be monotonic, and starts below 0.7V,
2. After reset occurs, all input and feedback setup times must be met before driving the clock pin high, and
3. The clock must remain stable during t_{PR}.

Figure 4-1. Power-up Reset Timing



4.8 Preload of Registered Outputs

The ATF22V10C's registers are provided with circuitry to allow loading of each register with either a high or a low. This feature will simplify testing since any state can be forced into the registers to control test sequencing. A JEDEC file with preload is generated when a source file with vectors is compiled. Once downloaded, the JEDEC file preload sequence will be done automatically by most of the approved programmers after the programming.

5. Electronic Signature Word

There are 64 bits of programmable memory that are always available to the user, even if the device is secured. These bits can be used for user-specific data.

6. Security Fuse Usage

A single fuse is provided to prevent unauthorized copying of the ATF22V10C fuse patterns. Once programmed, fuse verify and preload are inhibited. However, the 64-bit User Signature remains accessible.

The security fuse should be programmed last, as its effect is immediate.

7. Programming/Erasing

Programming/erasing is performed using standard PLD programmers. See “CMOS PLD Programming Hardware & Software Support” for information on software/programming.

Table 7-1. Programming/Erasing

Parameter	Description	Typ	Max	Units
t_{PR}	Power-up Reset Time	600	1,000	ns
V_{RST}	Power-up Reset Voltage	3.8	4.5	V

8. Input and I/O Pin-keeper Circuits

The ATF22V10C contains internal input and I/O pin-keeper circuits. These circuits allow each ATF22V10C pin to hold its previous value even when it is not being driven by an external source or by the device’s output buffer. This helps to ensure that all logic array inputs are at known valid logic levels. This reduces system power by preventing pins from floating to indeterminate levels. By using pin-keeper circuits rather than pull-up resistors, there is no DC current required to hold the pins in either logic state (high or low).

These pin-keeper circuits are implemented as weak feedback inverters, as shown in the Input Diagram below. These keeper circuits can easily be overdriven by standard TTL- or CMOS-compatible drivers. The typical overdrive current required is 40 µA.

Figure 8-1. Input Diagram

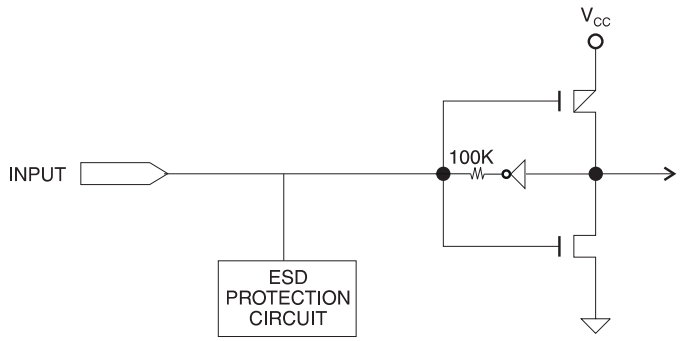
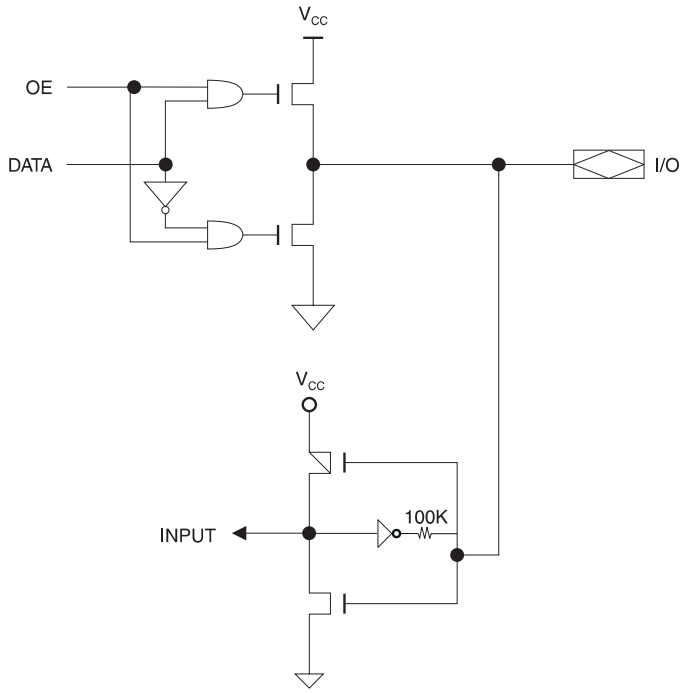


Figure 8-2. I/O Diagram



9. Power-down Mode

The ATF22V10C includes an optional pin-controlled power-down feature. When this mode is enabled, the PD pin acts as the power-down pin (Pin 4 on the DIP/SOIC packages and Pin 5 on the PLCC package). When the PD pin is high, the device supply current is reduced to less than 100 mA. During power-down, all output data and internal logic states are latched and held. Therefore, all registered and combinatorial output data remain valid. Any outputs that were in an undetermined state at the onset of power-down will remain at the same state. During power-down, all input signals except the power-down pin are blocked. Input and I/O hold latches remain active to ensure that pins do not float to indeterminate levels, further reducing system power. The power-down pin feature is enabled in the logic design file. Designs using the power-down pin may not use the PD pin logic array input. However, all other PD pin macrocell resources may still be used, including the buried feedback and foldback product term array inputs.

PD pin configuration is controlled by the design file, and appears as a separate fuse bit in the JEDEC file. When the power-down feature is not specified in the design file, the IN/PD pin will be configured as a regular logic input.

Note: Some programmers list the 22V10 JEDEC compatible 22V10C (no PD used) separately from the non-22V10 JEDEC compatible 22V10CEX (with PD used).

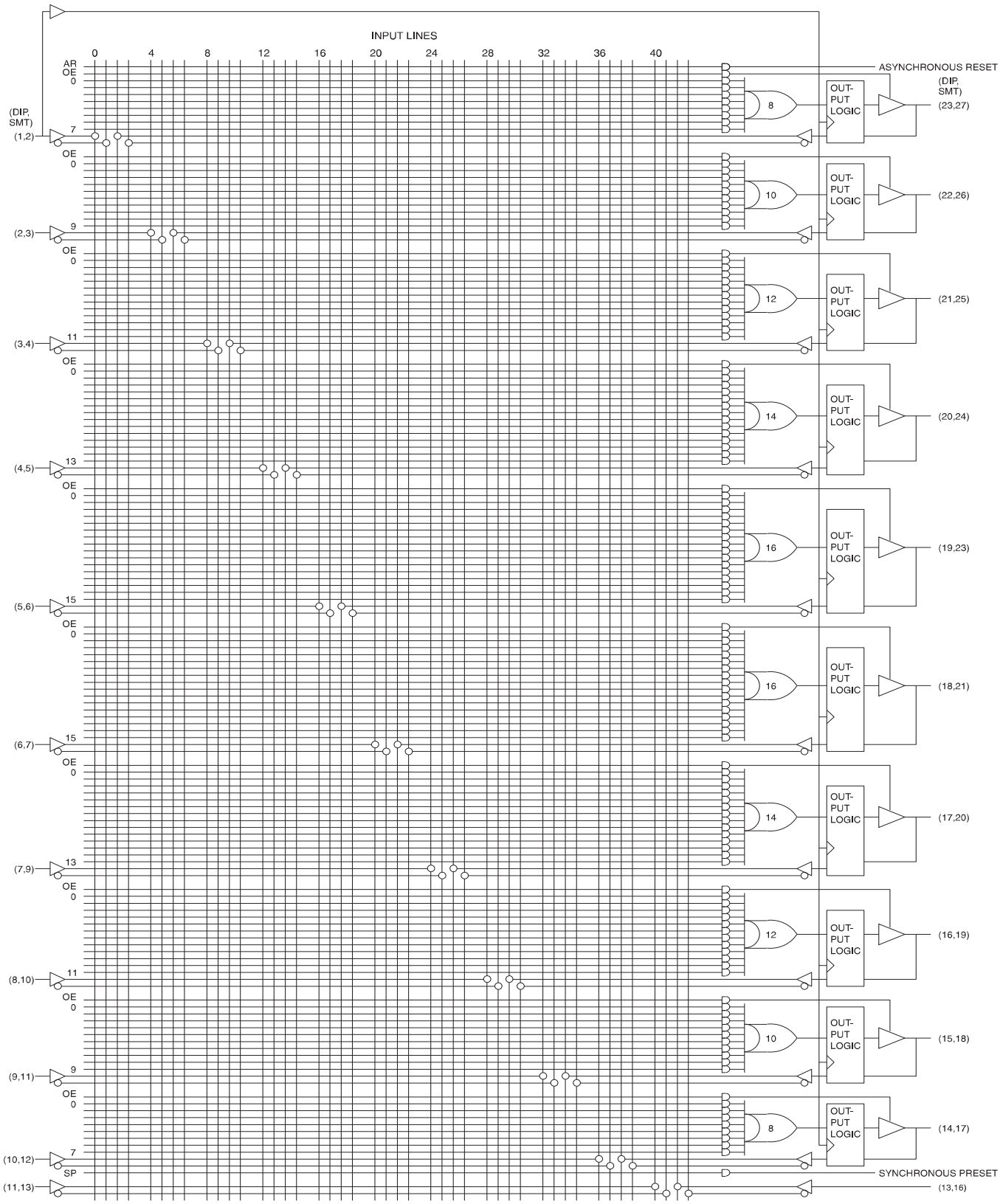
10. Compiler Mode Selection

Table 10-1. Compiler Mode Selection

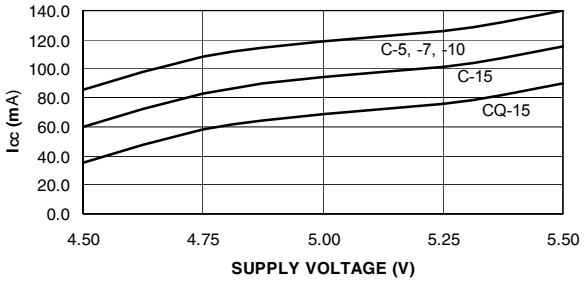
	PAL Mode (5828 Fuses)	GAL Mode (5892 Fuses)	Power-down Mode[1] (5893 Fuses)
Synario	ATF22V10C (DIP) ATF22V10C (PLCC)	ATTF22V10C DIP (UES) ATF22C10C PLCC (UES)	ATF22V10C DIP (PWD) ATF22V10C PLCC (PWD)
WINCUPL	P22V10 P22V10LCC	G22V10 G22V10LCC	G22V10CP G22V10CPLCC

Note: 1. These device types will create a JEDEC file which when programmed in ATF22V10C devices will enable the power-down mode feature. All other device types have the feature disabled.

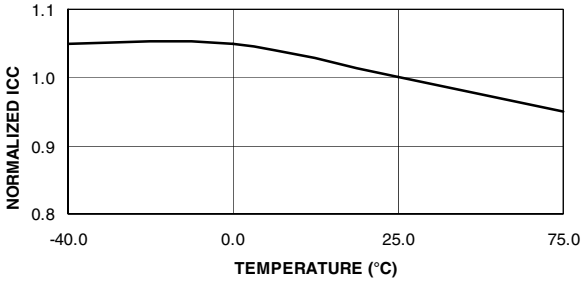
11. Functional Logic Diagram



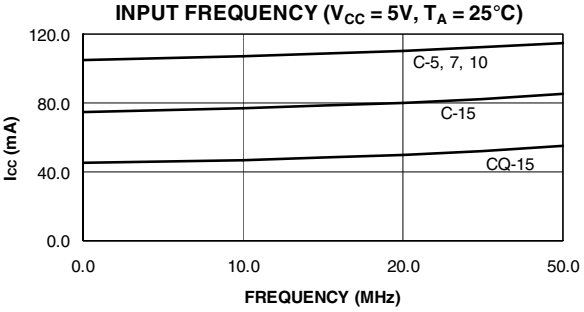
ATF22V10C/CQ SUPPLY CURRENT VS. SUPPLY VOLTAGE (T_A = 25°C)



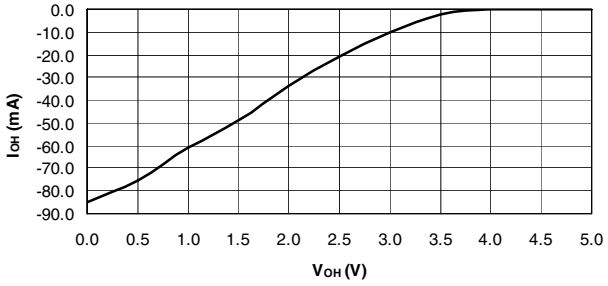
ATF22V10C/CQ NORMALIZED I_{CC} VS. TEMPERATURE



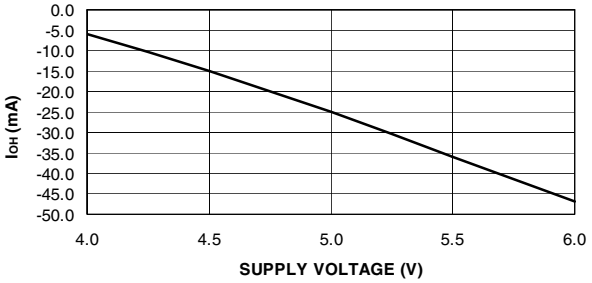
ATF22V10C/CQ SUPPLY CURRENT VS. INPUT FREQUENCY (V_{CC} = 5V, T_A = 25°C)



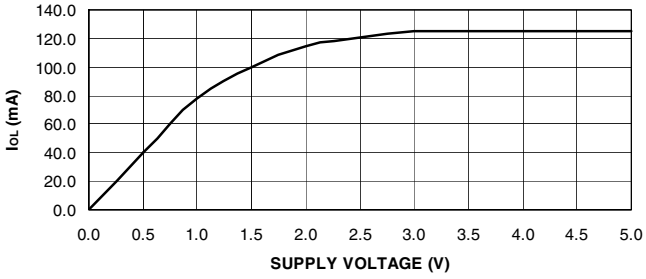
ATF22V10C/CQ OUTPUT SOURCE CURRENT VS. OUTPUT VOLTAGE (V_{CC} = 5V, T_A = 25°C)



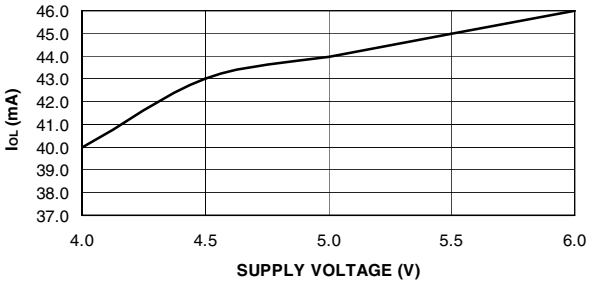
ATF22V10C/CQ OUTPUT SOURCE CURRENT VS. SUPPLY VOLTAGE (V_{OH} = 2.4V)



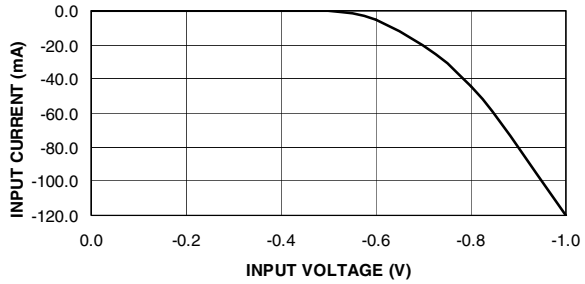
ATF22V10C/CQ OUTPUT SINK CURRENT VS. SUPPLY VOLTAGE (V_{OL} = 0.5V)



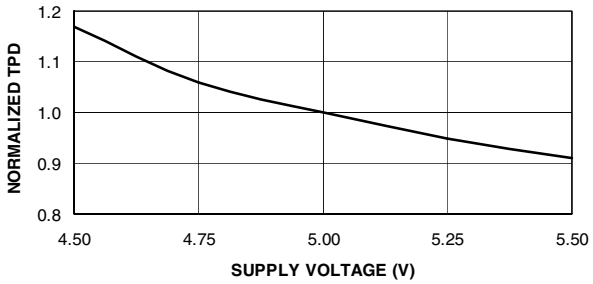
ATF22V10C/CQ OUTPUT SINK CURRENT VS. SUPPLY VOLTAGE (V_{OL} = 0.5V)



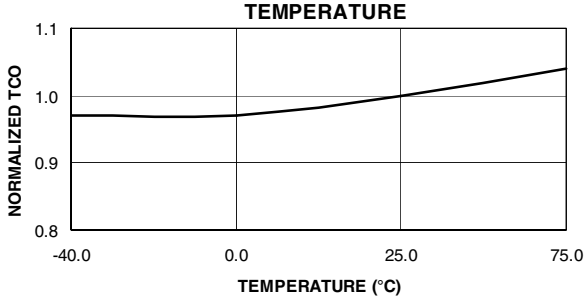
ATF22V10C/CQ INPUT CLAMP CURRENT VS. INPUT VOLTAGE (V_{CC} = 5V, T_A = 35°C)



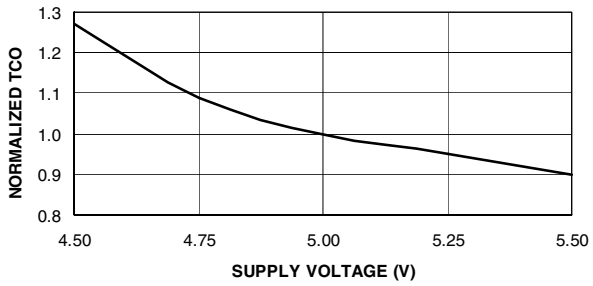
ATF22V10C/CQ NORMALIZED T_{PD} VS. V_{CC}



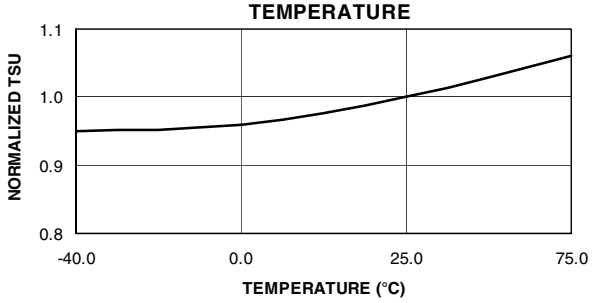
ATF22V10C/CQ NORMALIZED T_{CO} VS. TEMPERATURE



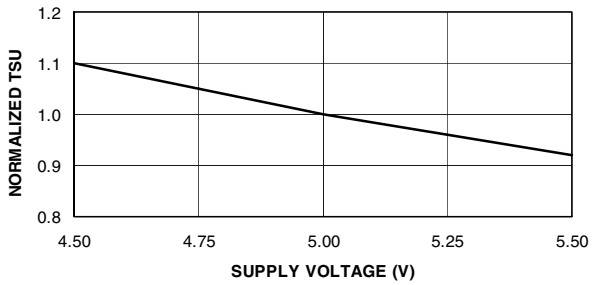
ATF22V10C/CQ NORMALIZED T_{CO} VS. V_{CC}



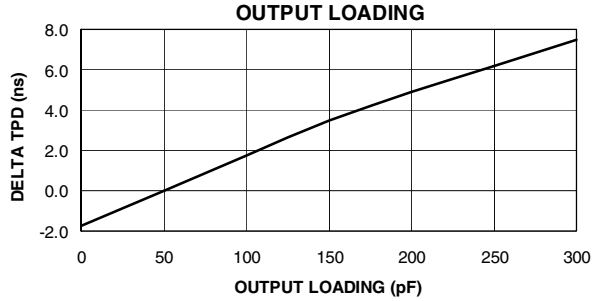
ATF22V10C/CQ NORMALIZED T_{SU} VS. TEMPERATURE



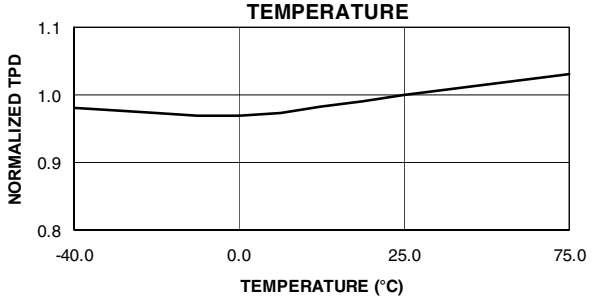
ATF22V10C/CQ NORMALIZED T_{SU} VS. V_{CC}



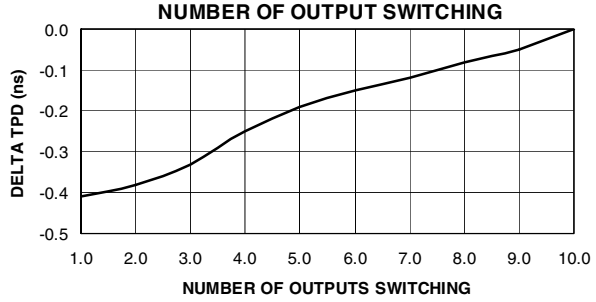
ATF22V10C/CQ DELTA T_{PD} VS. OUTPUT LOADING

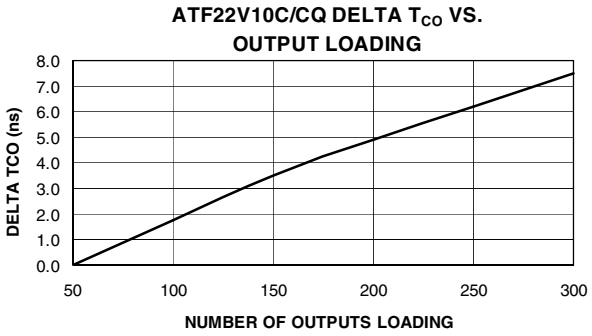


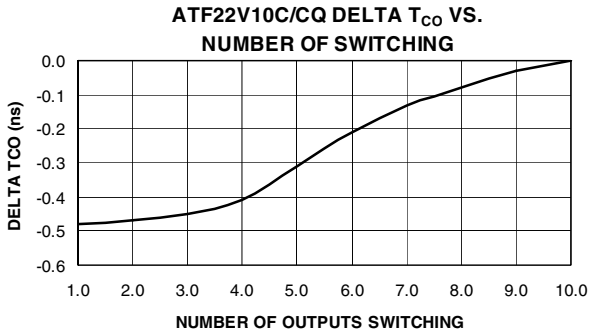
ATF22V10C/CQ NORMALIZED T_{PD} VS. TEMPERATURE



ATF22V10C/CQ DELTA T_{PD} VS. NUMBER OF OUTPUT SWITCHING




ATF22V10C/CQ DELTA T_{CO} VS.
OUTPUT LOADING
DELTA TCO (ns)
8.0
7.0
6.0
5.0
4.0
3.0
2.0
1.0
0.0
50
100
150
200
250
300
NUMBER OF OUTPUTS LOADING


ATF22V10C/CQ DELTA T_{CO} VS.
NUMBER OF SWITCHING
DELTA TCO (ns)
0.0
-0.1
-0.2
-0.3
-0.4
-0.5
-0.6
1.0
2.0
3.0
4.0
5.0
6.0
7.0
8.0
9.0
10.0
NUMBER OF OUTPUTS SWITCHING

12. Ordering Information

12.1 ATF22V10C(Q) Green Package Options (Pb/Halide-free/RoHS Compliant)

t_{PD} (ns)	t_S (ns)	t_{CO} (ns)	Ordering Code	Package	Operation Range
5	3	4	ATF22V10C-5JX	28J	Commercial (0°C to 70°C)
7.5	3.5	4.5	ATF22V10C-7PX ATF22V10C-7SX	24P3 24S	Commercial (0°C to 70°C)
7.5	3.5	4.5	ATF22V10C-7JU	28J	Industrial (-40°C to 85°C)
10	4.5	6.5	ATF22V10C-10JU ATF22V10C-10PU ATF22V10C-10SU ATF22V10C-10XU	28J 24P3 24S 24X	Industrial (-40°C to 85°C)
15	10	8	ATF22V10C-15JU ATF22V10C-15PU	28J 24P3	Industrial (-40°C to 85°C)
			ATF22V10CQ-15JU	28J	Industrial (-40°C to 85°C)

12.2 Using “C” Product for Industrial

To use commercial product for industrial temperature ranges, down-grade one speed grade from the industrial-grade to the commercial-grade device (e.g. 7 ns PX = 10 ns PU) and de-rate power by 30%.

12.3 Military Package Options (Lead-based)

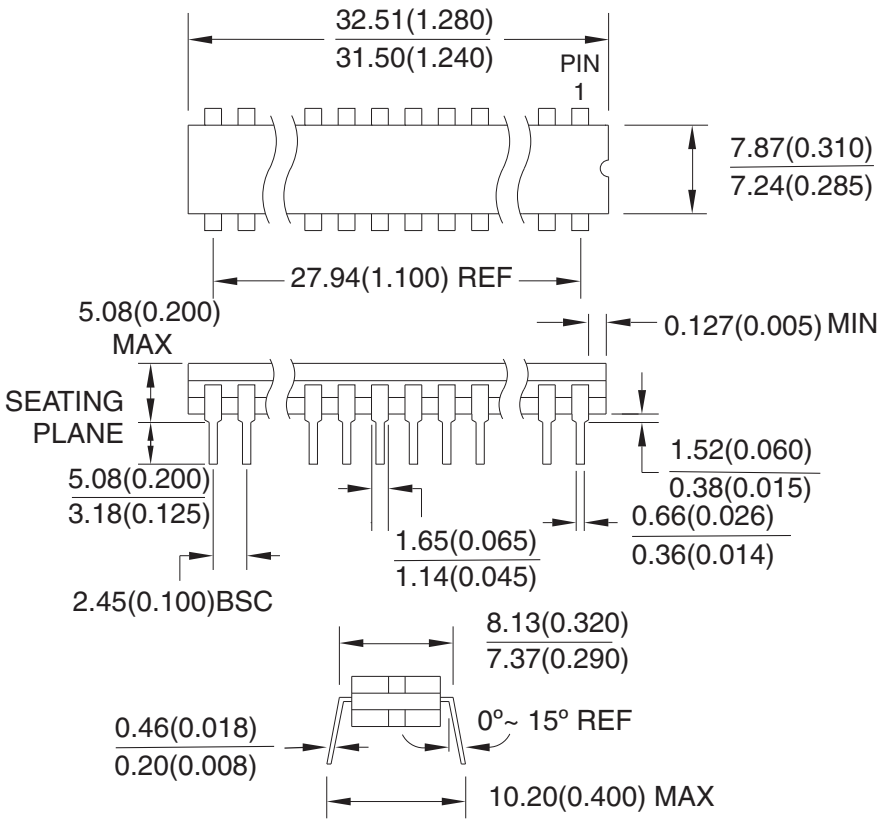
t_{PD} (ns)	t_S (ns)	t_{CO} (ns)	Ordering Code	Package	Operation Range
10	4.5	6.5	ATF22V10C-10GM/883 ATF22V10C-10NM/883	24D3 28L	Military (-55°C to 125°C) Class B, Fully Compliant
			5962-8984116LA 5962-89841163A	24D3 28L	
15	10	8	ATF22V10C-15GM/883 ATF22V10C-15NM/883	24D3 28L	Military (-55°C to 125°C) Class B, Fully Compliant
			5962-8984115LA 5962-89841153A	24D3 28L	

Package Type	
24D3	24-lead, 0.300" Wide, Non-windowed Ceramic Dual Inline Package (CERDIP)
24P3	24-pin, 0.300" Wide, Plastic Dual Inline Package (PDIP)
24S	24-lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)
24X	24-lead, 4.4 mm Wide, Plastic Thin Shrink Small Outline (TSSOP)
28J	28-lead, Plastic J-leaded Chip Carrier (PLCC)
28L	28-lead, Ceramic Leadless Chip Carrier (LCC)

13. Packaging Information

13.1 24D3 – CERDIP

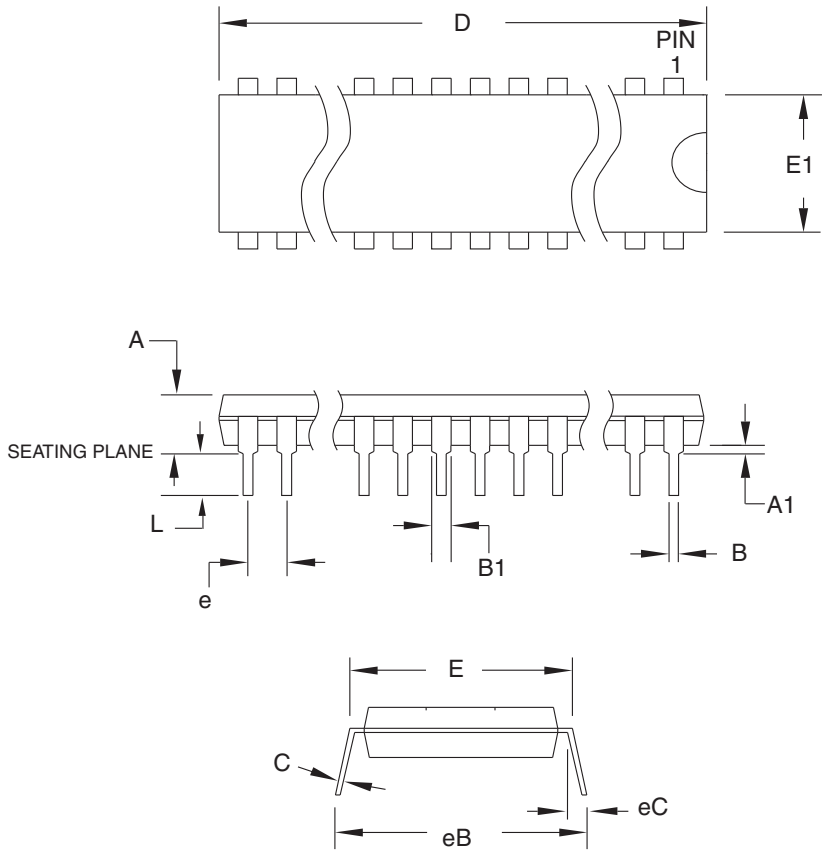
Dimensions in Millimeters and (Inches).
Controlling dimension: Inches.
MIL-STD 1835 D-9 Config A (Glass Sealed)



10/21/03

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**24D3**, 24-lead, 0.300" Wide. Non-windowed, Ceramic Dual Inline Package (Cerdip)	24D3	B

13.2 24P3 – PDIP



COMMON DIMENSIONS
(Unit of Measure = mm)

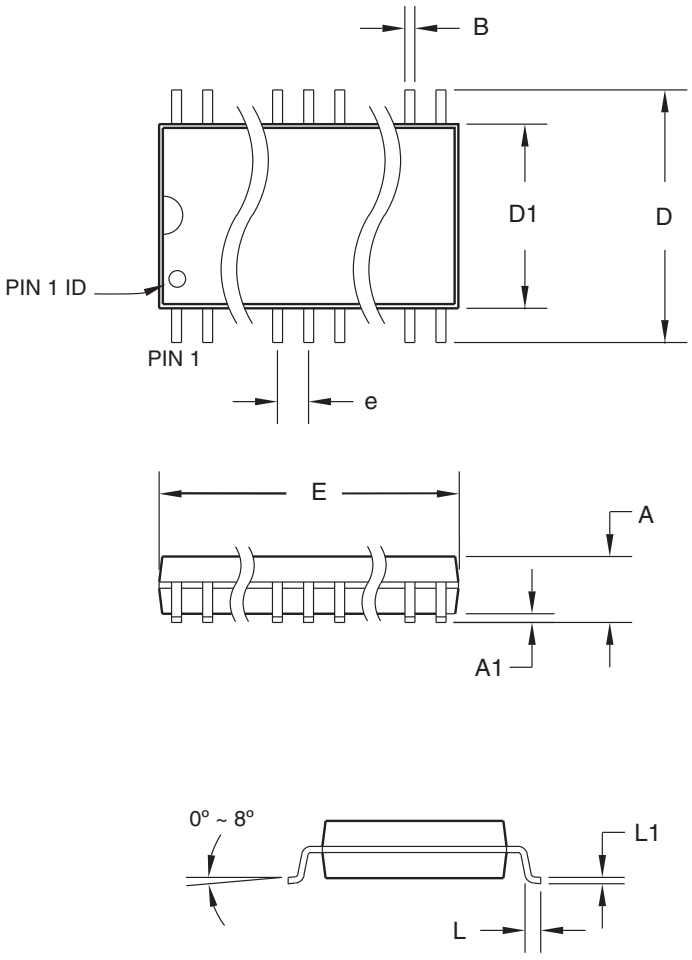
SYMBOL	MIN	NOM	MAX	NOTE
A	–	–	5.334	
A1	0.381	–	–	
D	31.623	–	32.131	Note 2
E	7.620	–	8.255	
E1	6.096	–	7.112	Note 2
B	0.356	–	0.559	
B1	1.270	–	1.651	
L	2.921	–	3.810	
C	0.203	–	0.356	
eB	–	–	10.922	
eC	0.000	–	1.524	
e	2.540 TYP			

Notes:
1. This package conforms to JEDEC reference MS-001, Variation AF.
2. Dimensions D and E1 do not include mold Flash or Protrusion. Mold Flash or Protrusion shall not exceed 0.25 mm (0.010").

6/1/04

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**24P3**, 24-lead (0.300"/7.62 mm Wide) Plastic Dual Inline Package (PDIP)	24P3	D

13.3 24S – SOIC



COMMON DIMENSIONS
(Unit of Measure = mm)

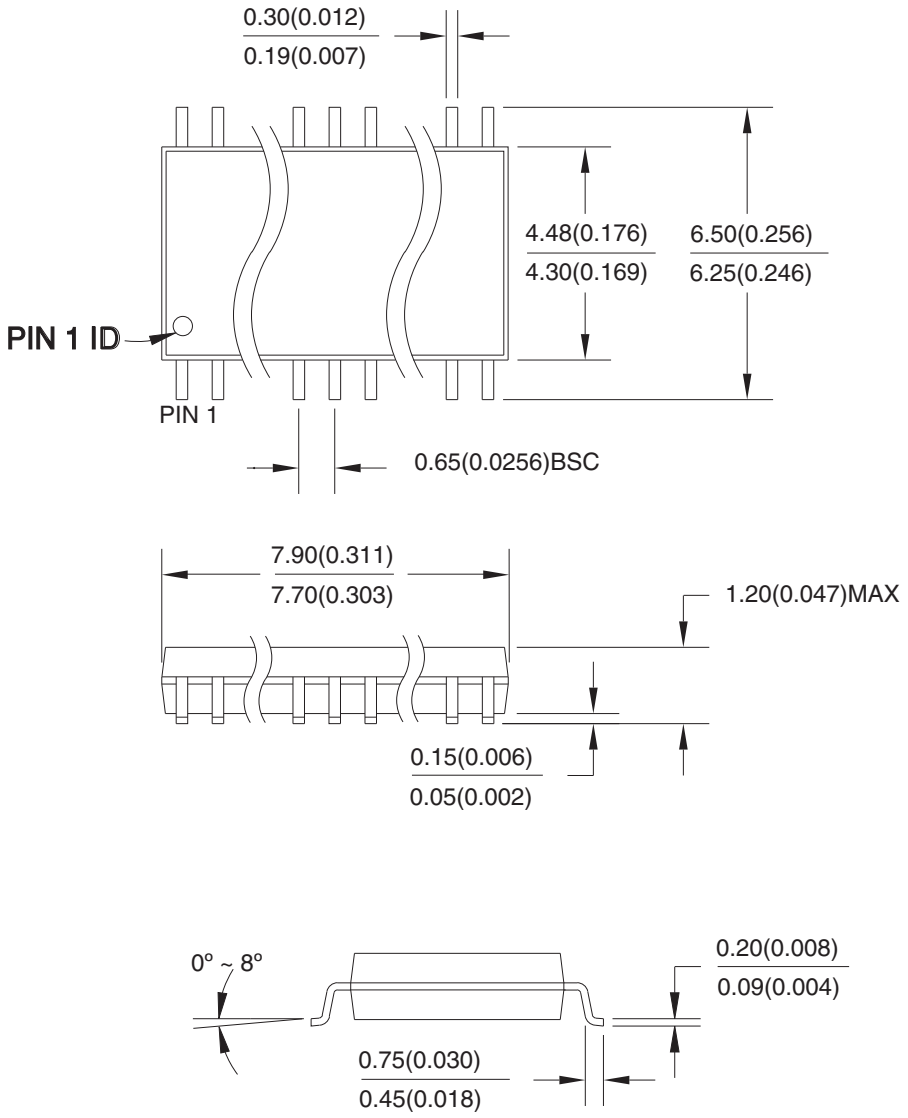
SYMBOL	MIN	NOM	MAX	NOTE
A	–	–	2.65	
A1	0.10	–	0.30	
D	10.00	–	10.65	
D1	7.40	–	7.60	
E	15.20	–	15.60	
B	0.33	–	0.51	
L	0.40	–	1.27	
L1	0.23	–	0.32	
e	1.27 BSC			

06/17/2002

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**24S**, 24-lead (0.300" body) Plastic Gull Wing Small Outline (SOIC)	24S	B

13.4 24X – TSSOP

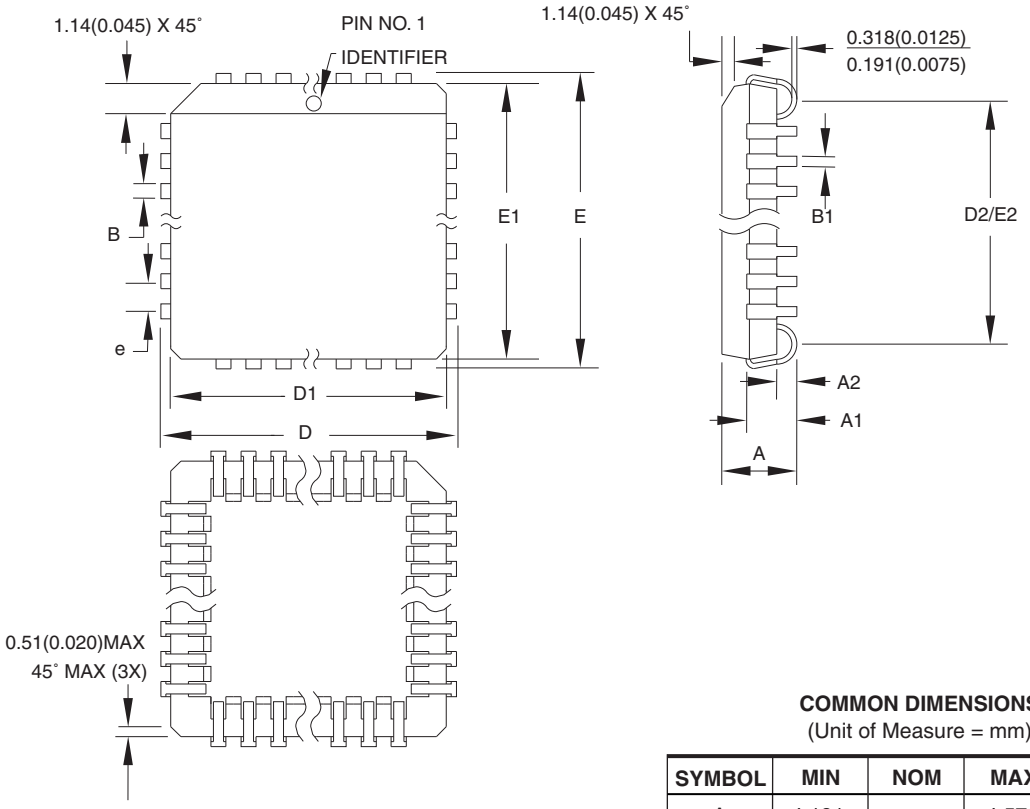
Dimensions in Millimeter and (Inches)*
JEDEC STANDARD MO-153 AD
Controlling dimension: millimeters



04/11/2001

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**24X**, 24-lead (4.4 mm body width) Plastic Thin Shrink Small Outline Package (TSSOP)	24X	A

13.5 28J – PLCC



COMMON DIMENSIONS
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
A	4.191	–	4.572	
A1	2.286	–	3.048	
A2	0.508	–	–	
D	12.319	–	12.573	
D1	11.430	–	11.582	Note 2
E	12.319	–	12.573	
E1	11.430	–	11.582	Note 2
D2/E2	9.906	–	10.922	
B	0.660	–	0.813	
B1	0.330	–	0.533	
e	1.270 TYP			

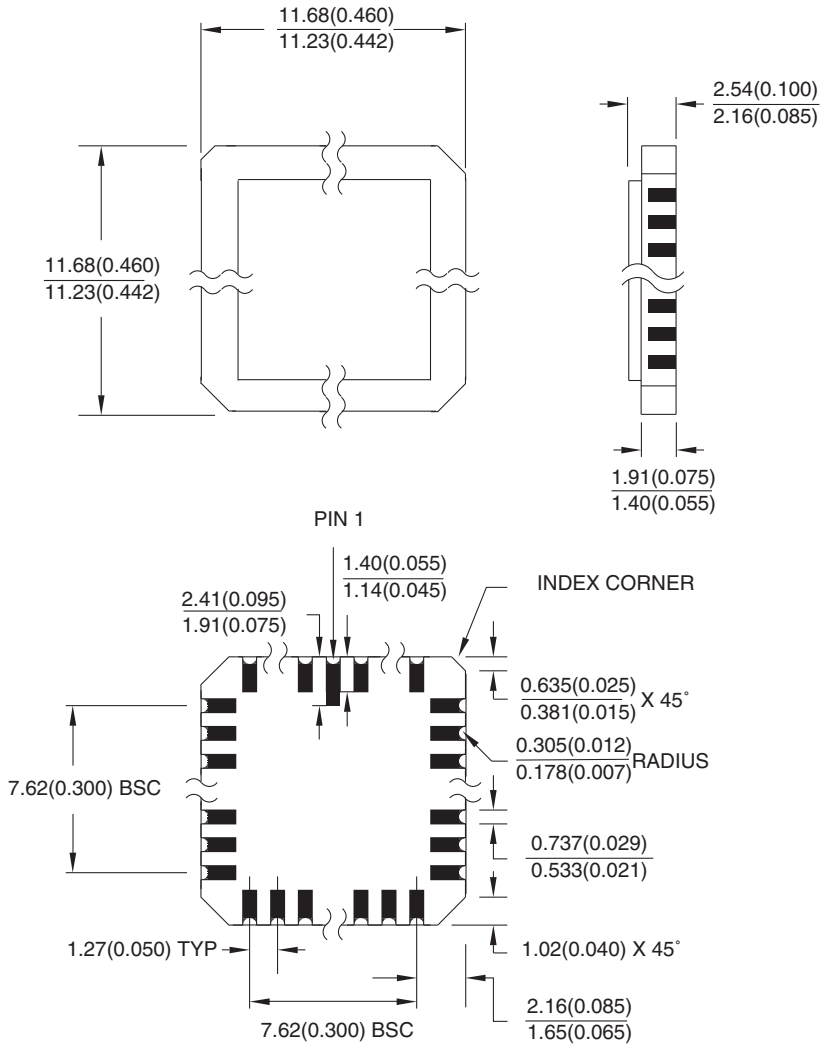
Notes:
1. This package conforms to JEDEC reference MS-018, Variation AB.
2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is .010"(0.254 mm) per side. Dimension D1 and E1 include mold mismatch and are measured at the extreme material condition at the upper or lower parting line.
3. Lead coplanarity is 0.004" (0.102 mm) maximum.

10/04/01

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**28J**, 28-lead, Plastic J-leaded Chip Carrier (PLCC)	28J	B

13.6 28L – LCC

Dimensions in Millimeters and (Inches).
Controlling dimension: Inches.
MIL-STD 1835 C-4



10/21/03

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	**28L**, 28-pad, Non-windowed, Ceramic Lid, Leadless Chip Carrier (LCC)	28L	B

14. Revision History

Revision Level – Revision Date	History
R – June 2006	Updated Green package options.
S – August 2008	Added new green part.
T – May 2009	Added military-grade packages and removed leaded parts.

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